

BC546B, BC547A, B, C, BC548B, C

Amplifier Transistors

NPN Silicon

Features

- Pb-Free Package is Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	65	Vdc
	BC546	45	
	BC547	30	
Collector-Base Voltage	V_{CBO}	80	Vdc
	BC546	50	
	BC548	30	
Emitter-Base Voltage	V_{EBO}	6.0	Vdc
Collector Current – Continuous	I_C	100	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625	mW
		5.0	mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5	Watt
		12	mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

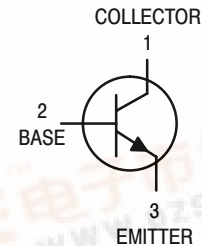
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

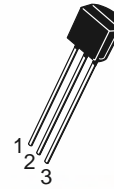


ON Semiconductor®

<http://onsemi.com>



MARKING DIAGRAM



TO-92
CASE 29
STYLE 17



BC54xx = Specific Device Code
Y = Year
WW = Work Week
■ = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I _C = 1.0 mA, I _B = 0)	BC546 BC547 BC548	V _{(BR)CEO}	65 45 30	– – –	– – –	V
Collector – Base Breakdown Voltage (I _C = 100 μAdc)	BC546 BC547 BC548	V _{(BR)CBO}	80 50 30	– – –	– – –	V
Emitter – Base Breakdown Voltage (I _E = 10 μA, I _C = 0)	BC546 BC547 BC548	V _{(BR)EBO}	6.0 6.0 6.0	– – –	– – –	V
Collector Cutoff Current (V _{CE} = 70 V, V _{BE} = 0) (V _{CE} = 50 V, V _{BE} = 0) (V _{CE} = 35 V, V _{BE} = 0) (V _{CE} = 30 V, T _A = 125°C)	BC546 BC547 BC548 BC546/547/548	I _{CES}	– – – –	0.2 0.2 0.2 –	15 15 15 4.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I _C = 10 μA, V _{CE} = 5.0 V)	BC547A BC546B/547B/548B BC548C	h _{FE}	– – –	90 150 270	– – –	–
(I _C = 2.0 mA, V _{CE} = 5.0 V)	BC546 BC547 BC548 BC547A BC546B/547B/548B BC547C/BC548C		110 110 110 110 200 420	– – – 180 290 520	450 800 800 220 450 800	
(I _C = 100 mA, V _{CE} = 5.0 V)	BC547A/548A BC546B/547B/548B BC548C		– – –	120 180 300	– – –	
Collector – Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.5 mA) (I _C = 100 mA, I _B = 5.0 mA) (I _C = 10 mA, I _B = See Note 1)		V _{CE(sat)}	– – –	0.09 0.2 0.3	0.25 0.6 0.6	V
Base – Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.5 mA)		V _{BE(sat)}	–	0.7	–	V
Base – Emitter On Voltage (I _C = 2.0 mA, V _{CE} = 5.0 V) (I _C = 10 mA, V _{CE} = 5.0 V)		V _{BE(on)}	0.55 –	– –	0.7 0.77	V
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product (I _C = 10 mA, V _{CE} = 5.0 V, f = 100 MHz)	BC546 BC547 BC548	f _T	150 150 150	300 300 300	– – –	MHz
Output Capacitance (V _{CB} = 10 V, I _C = 0, f = 1.0 MHz)		C _{obo}	–	1.7	4.5	pF
Input Capacitance (V _{EB} = 0.5 V, I _C = 0, f = 1.0 MHz)		C _{ibo}	–	10	–	pF
Small – Signal Current Gain (I _C = 2.0 mA, V _{CE} = 5.0 V, f = 1.0 kHz)	BC546 BC547/548 BC547A BC546B/547B/548B BC547C/548C	h _{fe}	125 125 125 240 450	– – 220 330 600	500 900 260 500 900	–
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2 kΩ, f = 1.0 kHz, Δf = 200 Hz)	BC546 BC547 BC548	NF	– – –	2.0 2.0 2.0	10 10 10	dB

1. I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.

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BC547/BC548

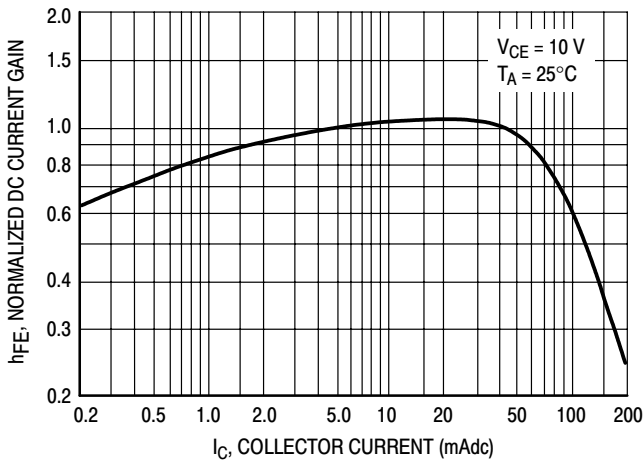


Figure 1. Normalized DC Current Gain

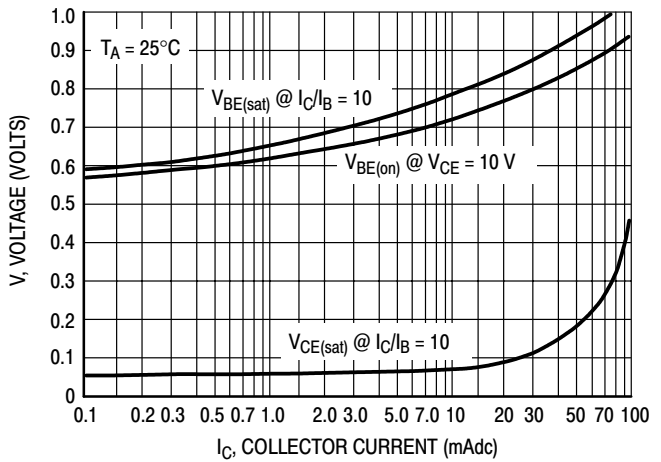


Figure 2. "Saturation" and "On" Voltages

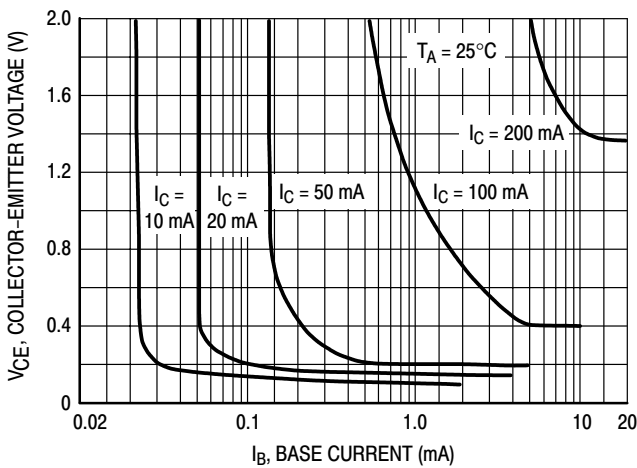


Figure 3. Collector Saturation Region

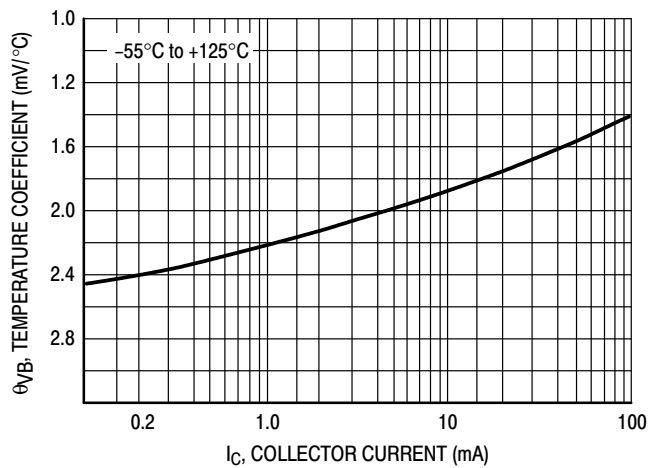


Figure 4. Base-Emitter Temperature Coefficient

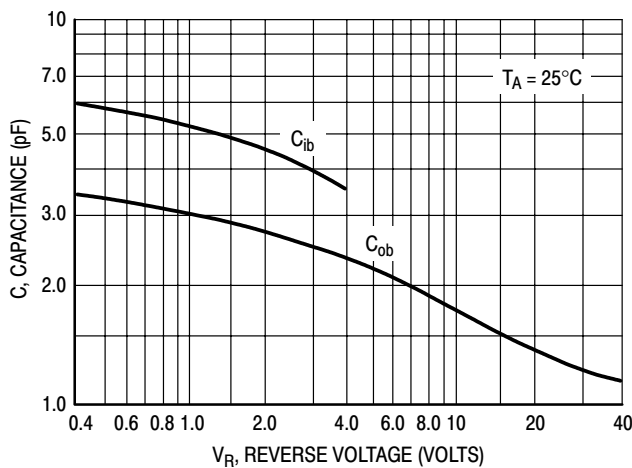


Figure 5. Capacitances

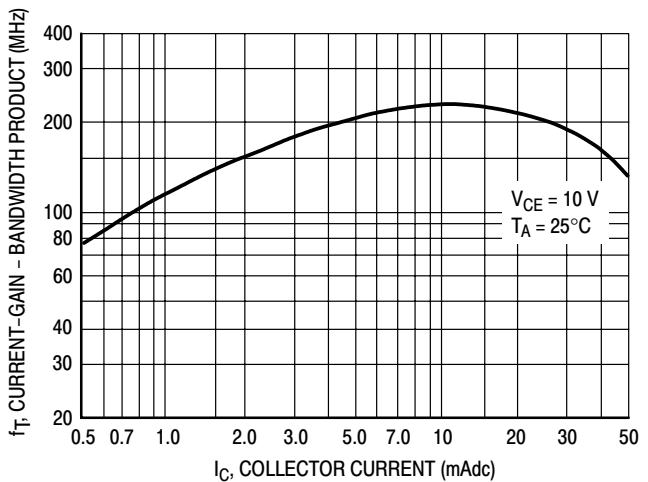


Figure 6. Current-Gain - Bandwidth Product

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BC546

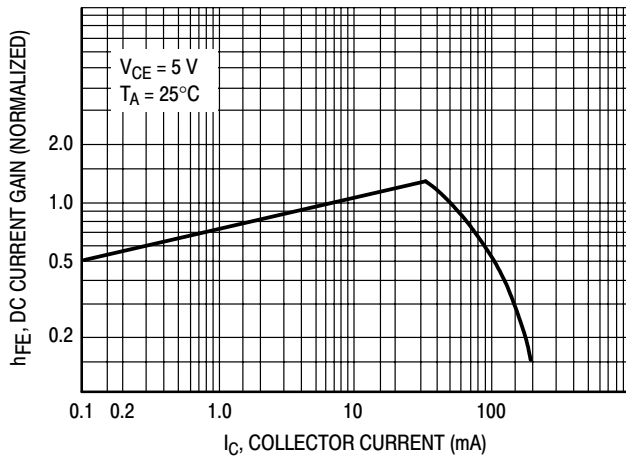


Figure 7. DC Current Gain

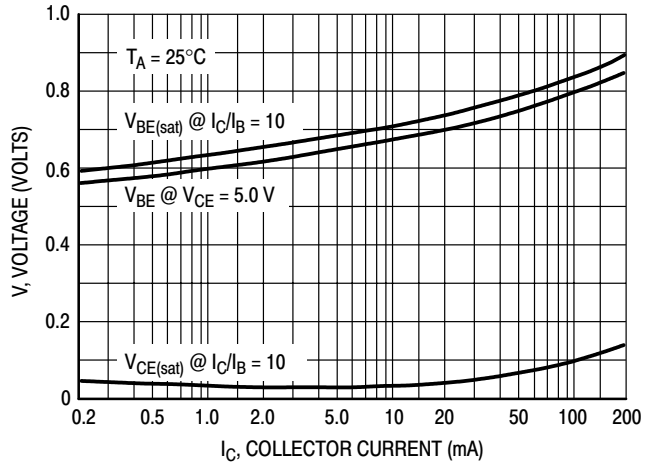


Figure 8. "On" Voltage

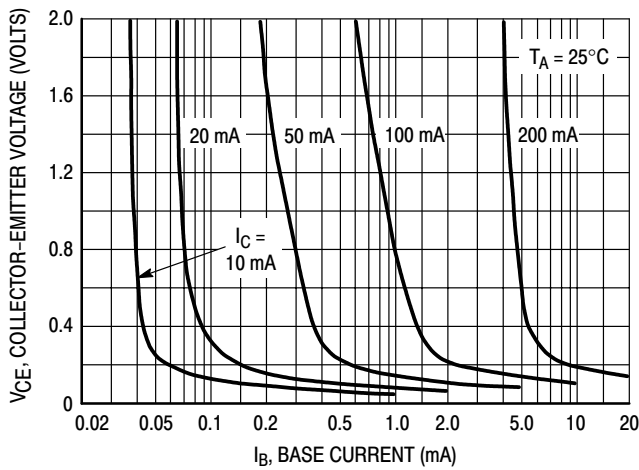


Figure 9. Collector Saturation Region

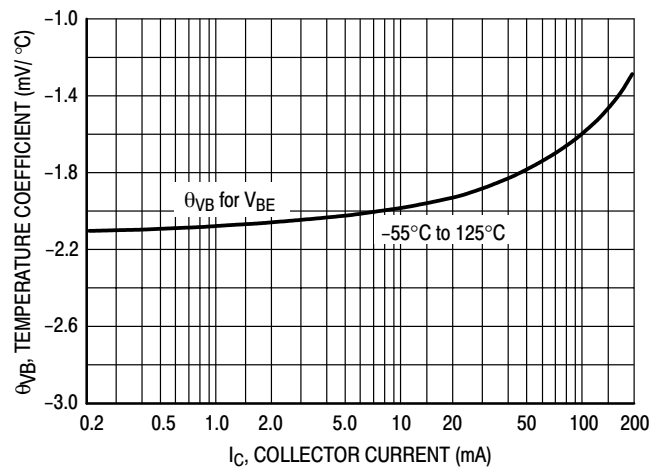


Figure 10. Base-Emitter Temperature Coefficient

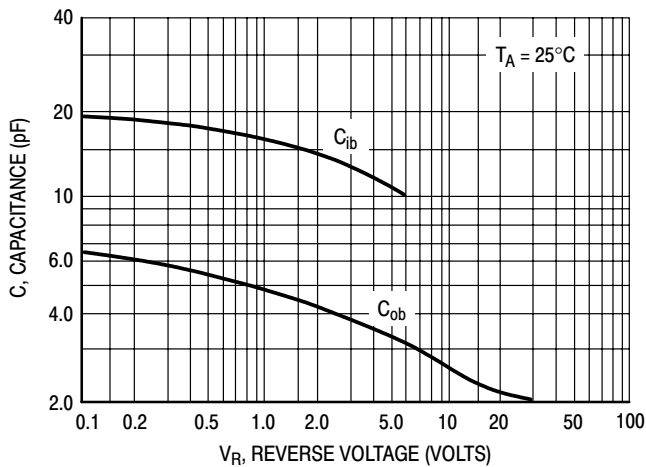


Figure 11. Capacitance

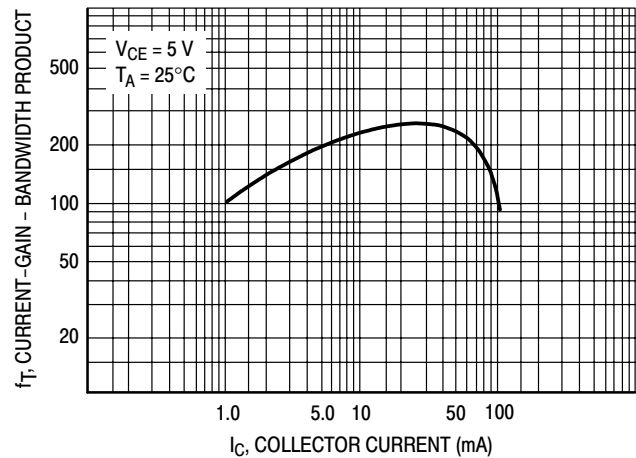


Figure 12. Current-Gain - Bandwidth Product

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DEVICE ORDERING INFORMATION

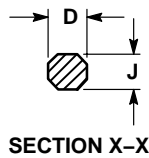
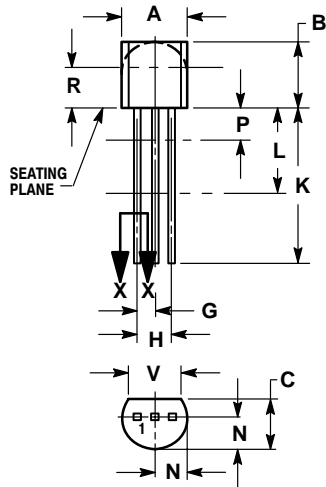
Device	Package	Shipping†
BC546B	TO-92 (TO-226)	5000 Units / Bulk
BC546BRL1		2000 Tape & Reel
BC546BZL1		2000 Tape & Ammo Box
BC547ARL		2000 Tape & Reel
BC547ARL1		2000 Tape & Reel
BC547AZL1		2000 Tape & Ammo Box
BC547B		5000 Units / Bulk
BC547BRL1		2000 Tape & Reel
BC547BZL1		2000 Tape & Ammo Box
BC547C		5000 Units / Bulk
BC547CZL1		2000 Tape & Ammo Box
BC548B		5000 Units / Bulk
BC548BRL1		2000 Tape & Reel
BC548BZL1		2000 Tape & Ammo Box
BC548BZL1G		
BC548C	TO-92 (TO-226)	5000 Units / Bulk
BC548CZL1		2000 Tape & Ammo Box

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BC546B, BC547A, B, C, BC548B, C

PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AL




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 17:

- PIN 1. COLLECTOR
- BASE
- EMITTER

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